## NSN 5961-00-807-5856

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

1.500 inches

## **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

0.200 inches

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Germanium

### Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 20.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

400.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 milliwatts small-signal input power, common-collector

#### **Transfer Ratio:**

20.0 small-signal short-circuit forward current transfer ratio, common-emitter

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/41 government specification

#### Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

